

MJ11021 (PNP) MJ11022 (NPN)

Complementary Darlington Silicon Power Transistors

Complementary Darlington Silicon Power Transistors are designed for use as general purpose amplifiers, low frequency switching and motor control applications.

Features

- High dc Current Gain @ 10 Adc – $h_{FE} = 400$ Min (All Types)
- Collector–Emitter Sustaining Voltage
 $V_{CEO(sus)} = 250$ Vdc (Min) – MJ11022, 21
- Low Collector–Emitter Saturation
 $V_{CE(sat)} = 1.0$ V (Typ) @ $I_C = 5.0$ A
 $= 1.8$ V (Typ) @ $I_C = 10$ A
- 100% SOA Tested @ $V_{CE} = 44$ V
 $I_C = 4.0$ A
 $t = 250$ ms
- Pb–Free Packages are Available*

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	250	Vdc
Collector–Base Voltage	V_{CBO}	250	Vdc
Emitter–Base Voltage	V_{EBO}	50	Vdc
Collector Current – Continuous – Peak (Note 1)	I_C	15 30	Adc
Base Current	I_B	0.5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate Above 25°C	P_D	175 1.16	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to $+175$ -65 to $+200$	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	0.86	$^\circ\text{C}/\text{W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

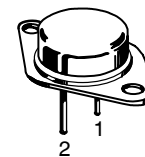
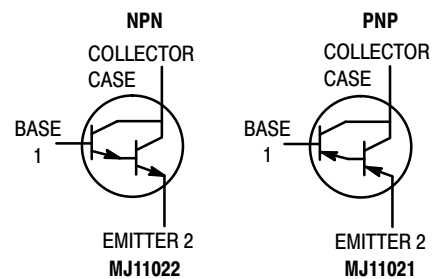
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

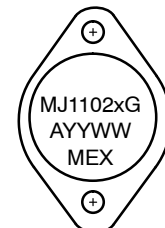
<http://onsemi.com>

15 AMPERE COMPLEMENTARY DARLINGTON POWER TRANSISTORS 250 VOLTS, 175 WATTS



**TO-204 (TO-3)
CASE 1-07
STYLE 1**

MARKING DIAGRAM



MJ1102x = Device Code
x = 1 or 2
G = Pb–Free Package
A = Location Code
YY = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
MJ11021	TO-3	100 Units/Tray
MJ11021G	TO-3 (Pb–Free)	100 Units/Tray
MJ11022	TO-3	100 Units/Tray
MJ11022G	TO-3 (Pb–Free)	100 Units/Tray

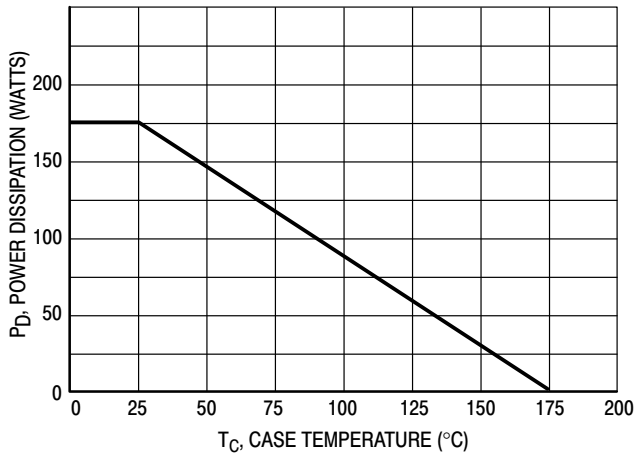
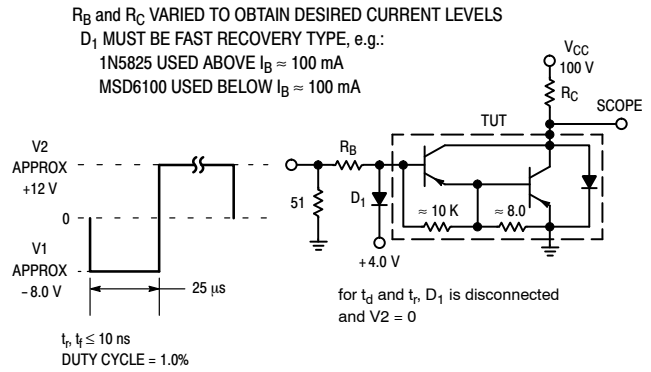


Figure 1. Power Derating



For NPN test circuit reverse diode and voltage polarities.

Figure 2. Switching Times Test Circuit

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 0.1$ Adc, $I_B = 0$)	$V_{CEO(sus)}$	250	–	Vdc
Collector Cutoff Current ($V_{CE} = 125$, $I_B = 0$)	I_{CEO}	–	1.0	mAdc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CB}$, $V_{BE(off)} = 1.5$ Vdc) ($V_{CE} = \text{Rated } V_{CB}$, $V_{BE(off)} = 1.5$ Vdc, $T_J = 150^\circ\text{C}$)	I_{CEV}	–	0.5 5.0	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0$ Vdc, $I_C = 0$)	I_{EBO}	–	2.0	mAdc

ON CHARACTERISTICS (Note 1)

DC Current Gain ($I_C = 10$ Adc, $V_{CE} = 5.0$ Vdc) ($I_C = 15$ Adc, $V_{CE} = 5.0$ Vdc)	h_{FE}	400 100	15,000 –	–
Collector–Emitter Saturation Voltage ($I_C = 10$ Adc, $I_B = 100$ mA) ($I_C = 15$ Adc, $I_B = 150$ mA)	$V_{CE(sat)}$	–	2.0 3.4	Vdc
Base–Emitter On Voltage $I_C = 10$ A, $V_{CE} = 5.0$ Vdc)	$V_{BE(on)}$	–	2.8	Vdc
Base–Emitter Saturation Voltage ($I_C = 15$ Adc, $I_B = 150$ mA)	$V_{BE(sat)}$	–	3.8	Vdc

DYNAMIC CHARACTERISTICS

Current–Gain Bandwidth Product ($I_C = 10$ Adc, $V_{CE} = 3.0$ Vdc, $f = 1.0$ MHz)	$[h_{fe}]$	3.0	–	Mhz
Output Capacitance ($V_{CB} = 10$ Vdc, $I_E = 0$, $f = 0.1$ MHz)	C_{ob}	–	400 600	pF
Small–Signal Current Gain ($I_C = 10$ Adc, $V_{CE} = 3.0$ Vdc, $f = 1.0$ kHz)	h_{fe}	75	–	–

SWITCHING CHARACTERISTICS

Characteristic	Symbol	Typical		Unit
		NPN	PNP	
Delay Time	t_d	150	75	ns
Rise Time	t_r	1.2	0.5	μs
Storage Time	t_s	4.4	2.7	μs
Fall Time	t_f	10.0	2.5	μs

$(V_{CC} = 100$ V, $I_C = 10$ A, $I_B = 100$ mA
 $V_{BE(off)} = 50$ V) (See Figure 2)

1. Pulsed Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

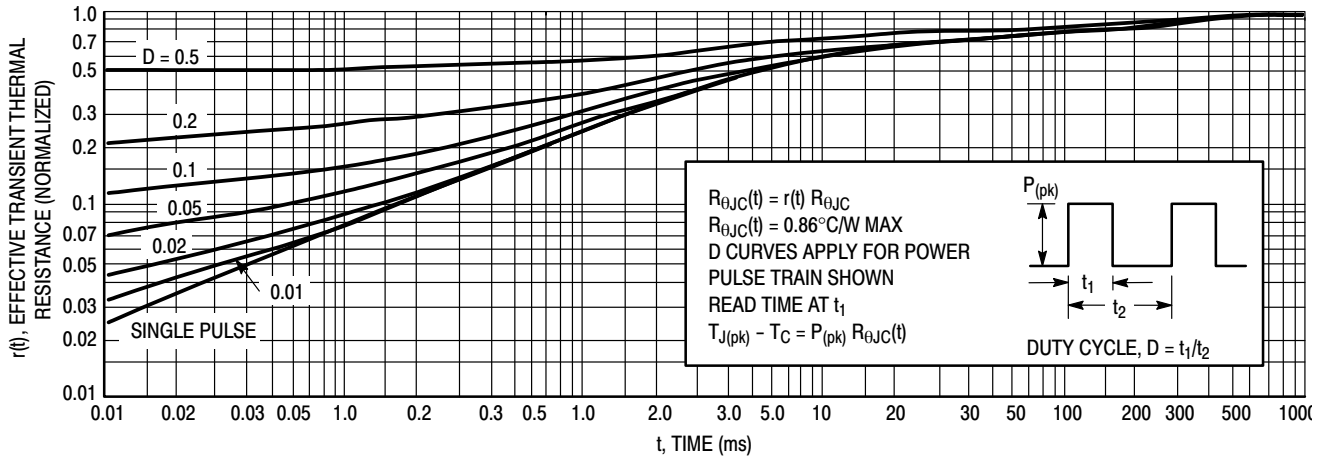


Figure 3. Thermal Response

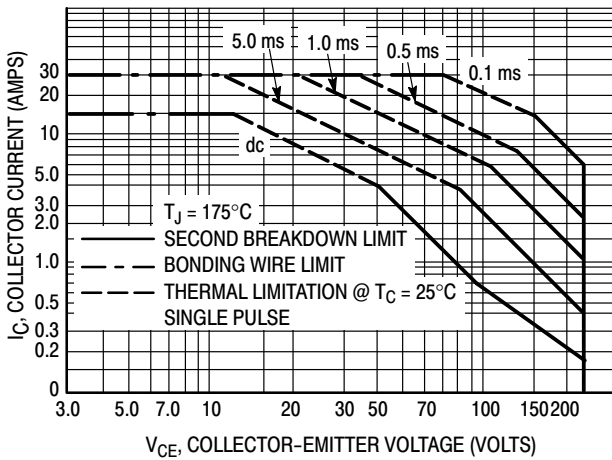


Figure 4. Maximum Rated Forward Bias Safe Operating Area (FBSOA)

FORWARD BIAS

There are two limitations on the power handling ability of a transistor average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 4 is based on $T_{J(pk)} = 175^\circ\text{C}$, T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 175^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 3. At high case temperatures thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

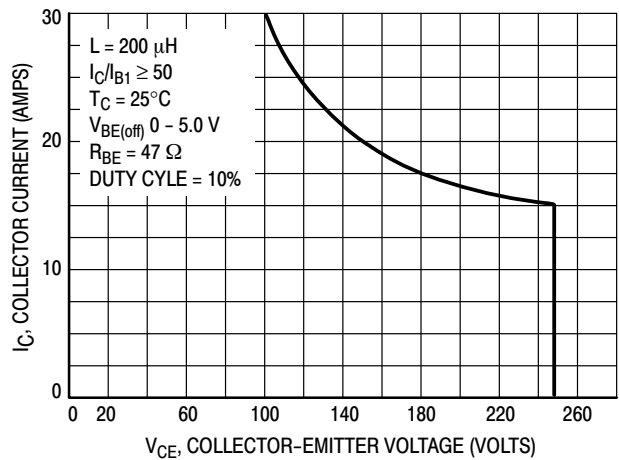


Figure 5. Maximum RBSOA, Reverse Bias Safe Operating Area

REVERSE BIAS

For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current conditions during reverse biased turn-off. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 5 gives ROSOA characteristics.

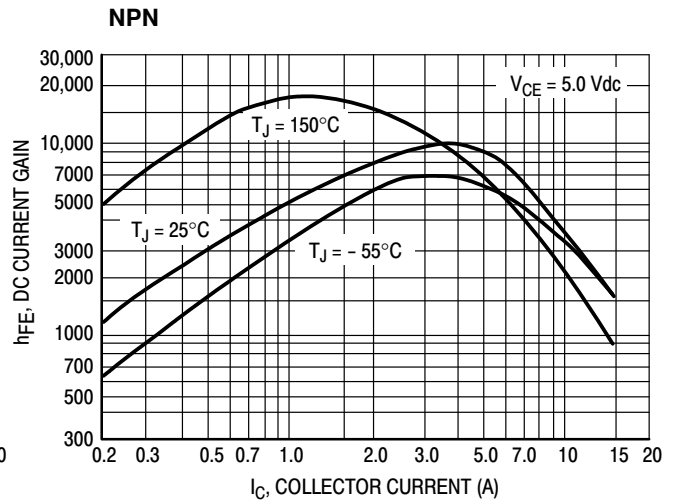
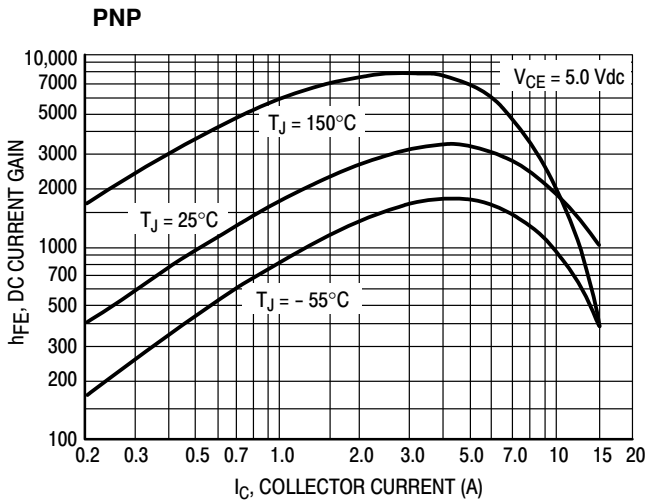


Figure 6. DC Current Gain

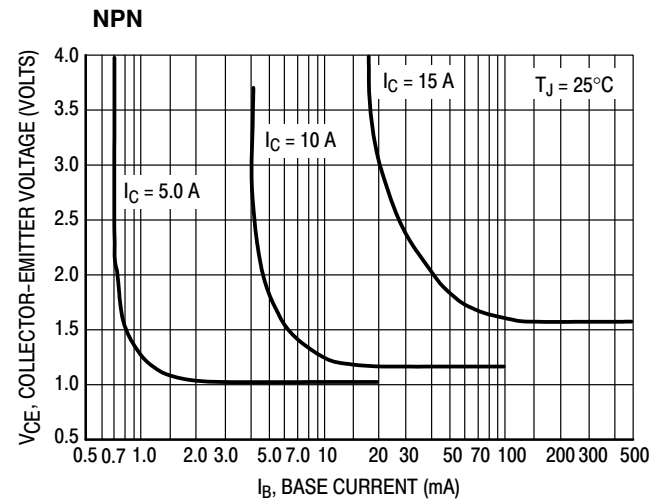
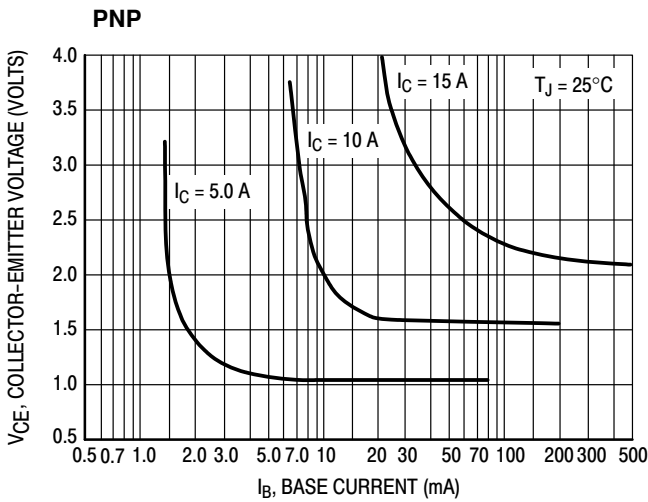


Figure 7. Collector Saturation Region

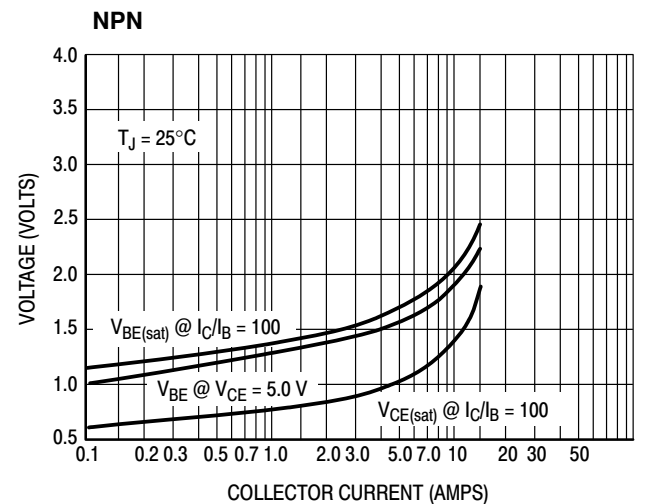
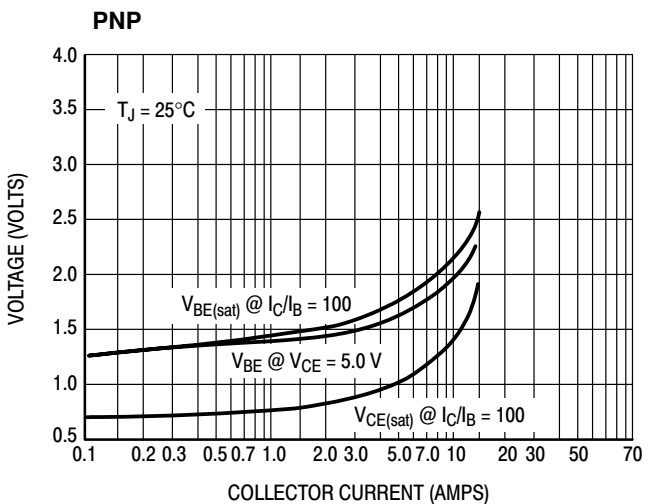


Figure 8. "On" Voltages

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor



TO-204 (TO-3)
CASE 1-07
ISSUE Z

DATE 05/18/1988



SCALE 1:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF	---	39.37 REF	---
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC	---	10.92 BSC	---
H	0.215 BSC	---	5.46 BSC	---
K	0.440	0.480	11.18	12.19
L	0.665 BSC	---	16.89 BSC	---
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC	---	30.15 BSC	---
V	0.131	0.188	3.33	4.77

- | | | | | |
|--|--|---|---|---|
| <p>STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 2:
PIN 1. BASE
2. COLLECTOR
CASE: EMITTER</p> | <p>STYLE 3:
PIN 1. GATE
2. SOURCE
CASE: DRAIN</p> | <p>STYLE 4:
PIN 1. GROUND
2. INPUT
CASE: OUTPUT</p> | <p>STYLE 5:
PIN 1. CATHODE
2. EXTERNAL TRIP/DELAY
CASE: ANODE</p> |
| <p>STYLE 6:
PIN 1. GATE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 7:
PIN 1. ANODE
2. OPEN
CASE: CATHODE</p> | <p>STYLE 8:
PIN 1. CATHODE #1
2. CATHODE #2
CASE: ANODE</p> | <p>STYLE 9:
PIN 1. ANODE #1
2. ANODE #2
CASE: CATHODE</p> | |

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